

KSR1003

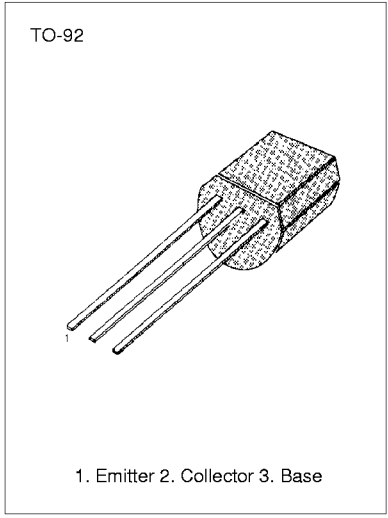
NPN EPITAXIAL SILICON TRANSISTOR

SWITCHING APPLICATION (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ($R_1=22K\Omega$, $R_2=22K\Omega$)
- Complement to KSR2003

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ C$)

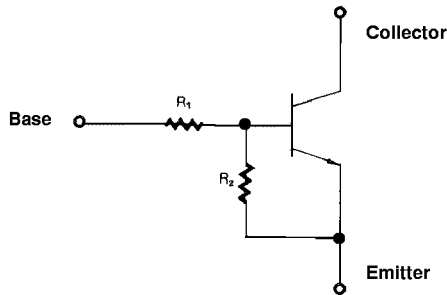
Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	10	V
Collector Current	I_C	100	mA
Collector Dissipation	P_C	300	mW
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature	T_{STG}	-55 ~ 150	$^\circ C$

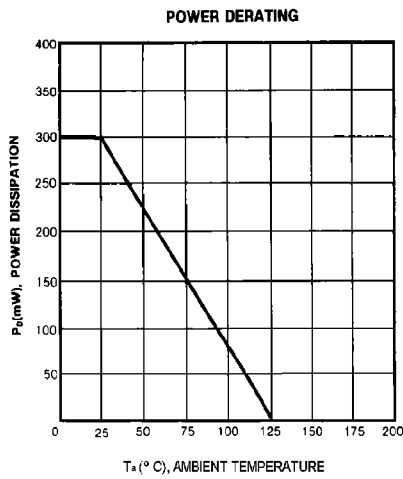
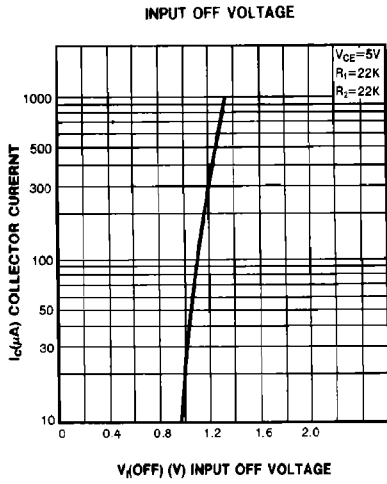
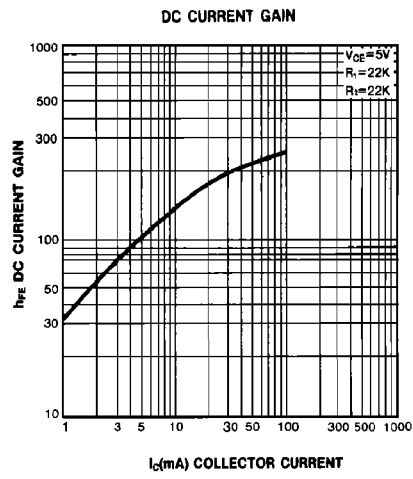
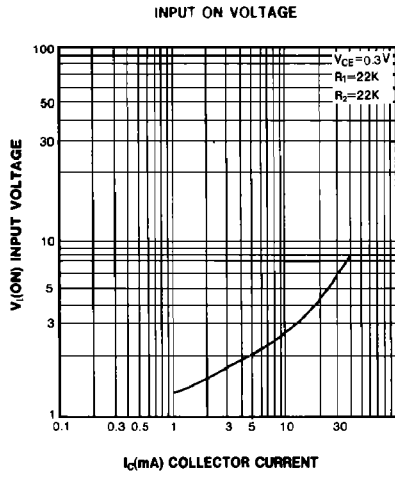


ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=10\mu A, I_E=0$	50			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=100\mu A, I_B=0$	50			V
Collector Cut-off Current	I_{CBO}	$V_{CB}=40V, I_E=0$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=5mA$	56			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=0.5mA$			0.3	V
Current Gain-Bandwidth Product	f_T	$V_{CE}=5mA, I_C=10V$		250		MHz
Output Capacitance	C_{OB}	$V_{CB}=10V, I_E=0$ $f=1.0MHz$		3.7		pF
Input Off Voltage	$V_I(off)$	$V_{CE}=5V, I_C=100\mu A$	0.5			V
Input On Voltage	$V_I(on)$	$V_{CE}=0.3V, I_C=5mA$			3.0	V
Input Resistor	R_1		15	22	29	$K\Omega$
Resistor Ratio	R_1/R_2		0.9	1	1.1	

EQUIVALENT CIRCUIT





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